INTEGRATED CIRCUITS

DATA SHEET

74ALS30A 8-Input NAND gate

Product specification

1991 Feb 08

IC05 Data Handbook





8-input NAND gate

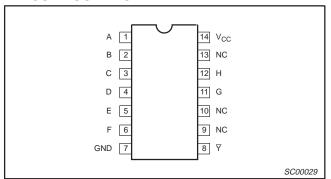
74ALS30A

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74ALS30A	5.0ns	0.5mA

ORDERING INFORMATION

	ORDER CODE		
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V $\pm 10\%$, T_{amb} = 0°C to ± 70 °C	DRAWING NUMBER	
14-pin plastic DIP	74ALS30AN	SOT27-1	
14-pin plastic SO	74ALS30AD	SOT108-1	

PIN CONFIGURATION

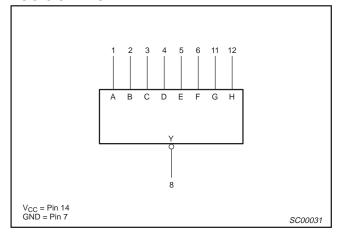


INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

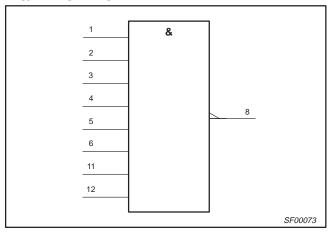
PINS	DESCRIPTION	74ALS (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
A – H	Data inputs	1.0/1.0	20μA/0.1mA
Y	Data output	20/80	0.4mA/8mA

NOTE: One (1.0) ALS unit load is defined as: 20μA in the High state and 0.1mA in the Low state.

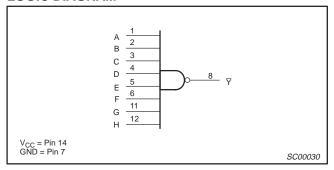
LOGIC SYMBOL



IEC/IEEE SYMBOL



LOGIC DIAGRAM



FUNCTION TABLE

			INP	JTS				OUTPUT
Α	В	С	D	Е	F	G	Н	Y
Н	Н	Н	Н	Н	Н	Н	Н	L
L	Х	Х	Χ	Х	Х	Х	Х	Н
Х	L	Х	Х	Х	Х	Х	Х	Н
Х	Х	L	Х	Х	Х	Х	Х	Н
Х	Х	Х	L	Х	Х	Х	Х	Н
Х	Х	Х	Χ	L	Х	Х	Х	Н
Х	Х	Х	Х	Х	L	Х	Х	Н
Х	Х	Х	Х	Х	Х	Ĺ	Х	Н
Χ	Χ	Х	Χ	Х	Х	Χ	L	Н

H = High voltage level
L = Low voltage level

X = Don't care

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ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	–0.5 to V _{CC}	V
I _{OUT}	Current applied to output in Low output state	16	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	DADAMETED		UNIT			
STIMBUL	PARAMETER	MIN	NOM	MAX		
V _{CC}	Supply voltage	4.5	5.0	5.5	V	
V _{IH}	High-level input voltage	2.0			V	
V _{IL}	Low-level input voltage			0.8	V	
I _{lk}	Input clamp current			-18	mA	
I _{OH}	High-level output current			-0.4	mA	
I _{OL}	Low-level output current		·	8	mA	
T _{amb}	Operating free-air temperature range	0		+70	°C	

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

CYMDOL	DADAMETER	TEST COMPITION	TEST CONDITIONS ¹				UNIT
SYMBOL	PARAMETER	TEST CONDITIONS	TEST CONDITIONS.			MAX	ONIT
V _{OH}	High-level output voltage	$V_{CC}\pm 10\%$, $V_{IL} = MAX$, $V_{IH} = MIN$	$I_{OH} = -0.4 \text{mA}$	V _{CC} – 2			V
V _{OL}	Low-level output voltage	$V_{CC} = MIN, V_{IL} = MAX,$	I _{OL} = 4mA		0.25	0.40	V
	Low-level output voltage	V _{IH} = MIN	I _{OL} = 8mA		0.35	0.50	V
V _{IK}	Input clamp voltage	$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.5	V	
I _I	Input current at maximum input voltage	$V_{CC} = MAX, V_I = 7.0V$			0.1	mA	
I _{IH}	High-level input current	$V_{CC} = MAX, V_I = 2.7V$			20	μΑ	
I _{IL}	Low-level input current	$V_{CC} = MAX, V_I = 0.5V$			-0.1	mA	
ΙO	Output current ³	$V_{CC} = MAX, V_O = 2.25V$		-30		-112	mA
1	Supply gurrent (total)	V _{CC} = MAX	$V_I = 0V$		0.20	0.36	mA
Icc	Supply current (total)	ACC = INIWY	V _I = 4.5V		0.64	0.9	mA

NOTES

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

2. All typical values are at V_{CC} = 5V, T_{amb} = 25°C.

3. The output conditions have been chosen to produce a current that closely approximate one half of the true short–circuit output current, I_{OS}.

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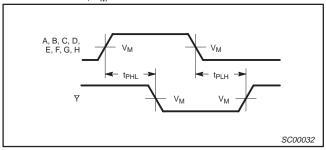
74ALS30A

AC ELECTRICAL CHARACTERISTICS

			LIM		
SYMBOL	PARAMETER	TEST CONDITION	T _{amb} = 0°C V _{CC} = +5. C _L = 50pF,	UNIT	
			MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay A, B, C, D, E, F, G, H to $n\overline{Y}$	Waveform 1	2.0 3.0	8.0 10.0	ns

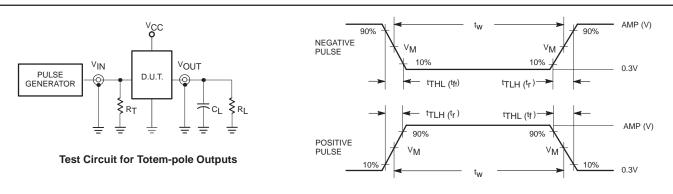
AC WAVEFORMS

For all waveforms, $V_M = 1.3V$.



Waveform 1. Propagation Delay for Data to Output

TEST CIRCUIT AND WAVEFORMS



DEFINITIONS:

R_L = Load resistor;

see AC electrical characteristics for value.

C_L = Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

_		
Input	Pulse	Definition

Family		INPUT PULSE REQUIREMENTS							
	Amplitude	V_{M}	Rep.Rate	t _w	t _{TLH}	t _{THL}			
74ALS	3.5V	1.3V	1MHz	500ns	2.0ns	2.0ns			

SC00005

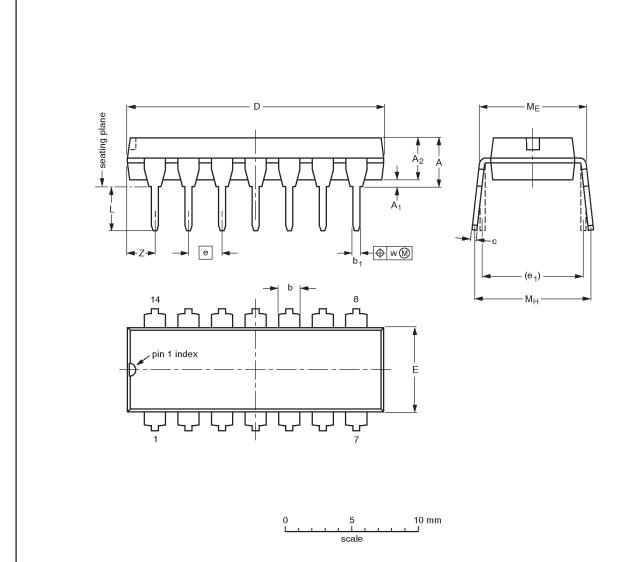
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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE				
	VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
	SOT27-1	050G04	MO-001AA				92-11-17 95-03-11	

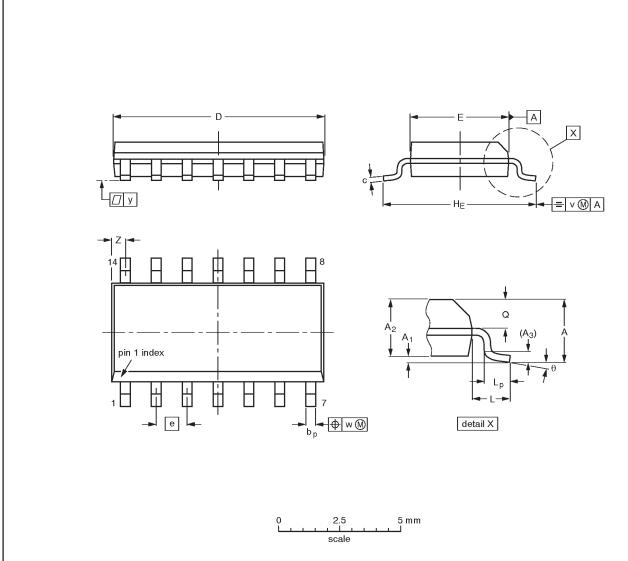
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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039	0.057 0.049	0.01		0.0098 0.0075		0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB				91-08-13 95-01-23	

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DEFINITIONS							
Data Sheet Identification	Product Status	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
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